

TS27M2, TS27M2A, TS27M2B

Low-power CMOS dual operational amplifiers

Features

■ Wide supply voltage range: 3 to 16 V

■ Ultra-low consumption: 150 µA/op typ

Output voltage swing to ground

■ Excellent phase margin on capacitive load

■ Gain bandwidth product: 1 MHz typ

■ Vio down to 2 mV max. (B version)

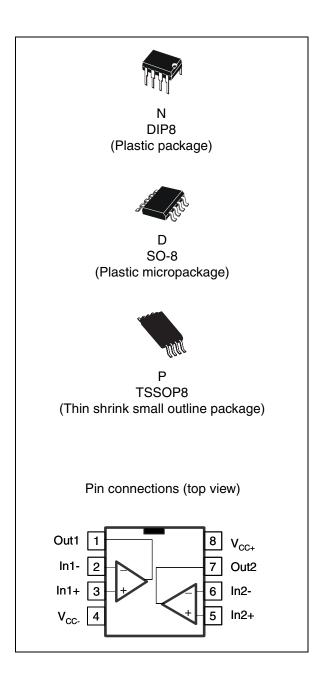
Description

The TS27x2 series are low-cost and low-power dual operational amplifiers designed to operate with high-voltage single or dual supplies. These operational amplifiers use the ST silicon gate CMOS process, providing an excellent consumption-speed ratio thanks to three different power consumptions, making them ideal for low-consumption applications:

 I_{CC} = 10 μ A/amp: TS27L2 (very low power), I_{CC} = 150 μ A/amp: TS27M2 (low power) and

I_{CC} = 1 mA/amp: TS272 (high speed)

The devices also offer a very high input impedance and extremely low input currents. Their main advantage compared to JFET devices is the very low input current drift with temperature (*Figure 3*).



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Absolute maximum ratings and operating conditions

Table 1. **Absolute maximum ratings**

Symbol	Parameter	TS27M2x/Ax/Bx	Unit
V _{CC} ⁺	Supply voltage (1)	18	V
Vid	Differential input voltage (2)	±18	V
V _i	Input voltage (3)	-0.3 to 18	V
Io	Output current for V _{CC} ⁺ ≥ 15V	±30	mA
I _{in}	Input current	±5	mA
R _{thja} ⁽⁴⁾⁽⁵⁾	SO-8 DIP8 TSSOP8	125 85 120	°C/W
T _{stg}	Storage temperature range	-65 to +150	°C
T _j	Maximum junction temperature	150	°C
	HBM: human body model ⁽⁶⁾	500	V
ESD	MM: machine model ⁽⁷⁾	100	V
	CDM: charged device model ⁽⁸⁾	1.5	kV

- 1. All values, except differential voltage are with respect to network ground terminal.
- 2. Differential voltages are the non-inverting input terminal with respect to the inverting input terminal.
- The magnitude of the input and the output voltages must never exceed the magnitude of the positive supply voltage.
- 4. Short-circuits can cause excessive heating and destructive dissipation.
- 5. Rth are typical values.
- Human body model: a 100 pF capacitor is charged to the specified voltage, then discharged through a $1.5~\mathrm{k}\Omega$ resistor between two pins of the device. This is done for all couples of connected pin combinations while the other pins are floating.
- 7. Machine model: a 200 pF capacitor is charged to the specified voltage, then discharged directly between two pins of the device with no external series resistor (internal resistor $< 5 \Omega$). This is done for all couples of connected pin combinations while the other pins are floating.
- Charged device model: all pins and the package are charged together to the specified voltage and then discharged directly to the ground through only one pin. This is done for all pins.

Operating conditions Table 2.

Symbol	Parameter	Value				
Symbol	raiailletei	TS27M2C/AC/BC	TS27M2I/AI/BI	TS27M2M/AM/BM		
V _{CC} ⁺	Supply voltage	3 to 16			V	
V _{icm}	Common mode input voltage range	0 to V _{CC} ⁺ - 1.5			V	
Toper	Operating free air temperature range	0 to +70	-40 to +125	-55 to +125	°C	

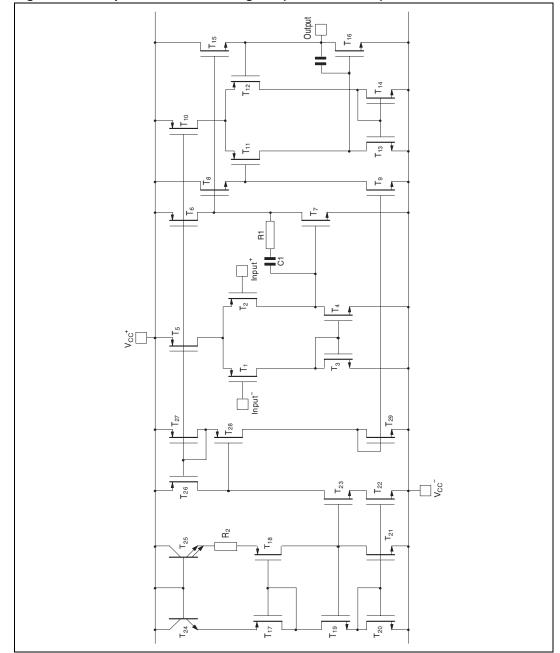


Figure 1. Simplified schematic diagram (for 1/2 TS27M2)

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2 Electrical characteristics

Table 3. Electrical characteristics at V_{CC} + = +10 V, V_{CC} - = 0 V, T_{amb} = +25° C (unless otherwise specified)

Symbol	Parameter	т	TS27M2xC			S27M2 S27M2	Unit	
		Min.	Тур.	Max.	Min.	Тур.	Max.	
DC perfo	rmance							
V _{io}	Input offset voltage $V_O = 1.4 \text{ V, } V_{ic} = 0 \text{ V} \qquad \text{TS27M2} \\ \qquad \qquad \qquad \qquad \text{TS27M2A} \\ \qquad \qquad \qquad \qquad \text{TS27M2B} \\ T_{min} \leq T_{amb} \leq T_{max} \qquad \qquad \text{TS27M2} \\ \qquad \qquad \qquad \qquad \qquad \qquad \text{TS27M2A} \\ \qquad \qquad \qquad \qquad \qquad \qquad \qquad \qquad \text{TS27M2B} \\ \qquad $		1.1 0.9 0.25	10 5 2 12 6.5 3		1.1 0.9 0.25	10 5 2 12 6.5 3.5	mV
DV _{io}	Input offset voltage drift		2			2		μV/°C
l _{io}	Input offset current ⁽¹⁾ $V_{ic} = 5 \text{ V}, V_O = 5 \text{ V}$ $T_{min} \leq T_{amb} \leq T_{max}$		1	100		1	200	рА
I _{ib}	Input bias current ⁽¹⁾ $V_{ic} = 5 \text{ V, } V_{O} = 5 \text{ V}$ $T_{min} \leq T_{amb} \leq T_{max}$		1	150		1	300	рА
V _{OH}	High level output voltage V_{id} = 100 mV, R_L = 100 lΩ $T_{min} \le T_{amb} \le T_{max}$	8.7 8.6	8.9		8.7 8.5	8.9		٧
V _{OL}	Low level output voltage V _{id} = -100 mV			50			50	mV
A _{vd}	Large signal voltage gain $\begin{aligned} &V_{iC} = 5 \text{ V, } R_L = 100 \text{ k}\Omega, V_o = 1 \text{ V to 6 V} \\ &T_{min} \leq &T_{amb} \leq &T_{max} \end{aligned}$	30 20	50		30 10	50		V/mV
CMR	Common mode rejection ratio $V_{iC} = 1 \text{ V to } 7.4 \text{ V, } V_o = 1.4 \text{ V}$	65	80		65	80		dB
SVR	Supply voltage rejection ratio $V_{CC}^+ = 5 \text{ V to } 10 \text{ V}, V_0 = 1.4 \text{ V}$	60	80		60	80		dB
I _{CC}	Supply current (per amplifier) $A_{V} = 1, \text{ no load, } V_{O} = 5 \text{ V}$ $T_{min} \leq T_{amb} \leq T_{max}$		150	200 250		150	200 300	μА
I _o	Output short circuit current $V_0 = 0 \text{ V}, V_{id} = 100 \text{ mV}$	45	60			60		mA
I _{sink}	Output sink current $V_o = V_{CC}$, $V_{id} = -100 \text{ mV}$	34	45			45		mA

Table 3. Electrical characteristics at V_{CC} + = +10 V, V_{CC} - = 0 V, T_{amb} = +25° C (unless otherwise specified) (continued)

Symbol Parameter		TS27M2xC			TS27M2xI TS27M2xM			Unit
		Min.	Тур.	Max.	Min.	Тур.	Max.	
AC perfor	mance							
GBP	Gain bandwidth product $A_{V}=40~\text{dB, R}_{L}=100~\text{k}\Omega,~~C_{L}=100~\text{pF,}$ $f_{in}=100~\text{kHz}$	0.5	1		0.5	1		MHz
SR	Slew rate at unity gain $R_L = 100 \text{ k}\Omega \text{ C}_L = 100 \text{ pF, V}_i = 3 \text{ to 7 V}$		0.6		0.3	0.6		V/μs
φm	Phase margin at unity gain $A_v = 40 \text{ dB}, R_L = 100 \text{ k}\Omega, C_L = 100 \text{ pF}$		45			45		Degrees
K _{OV}	Overshoot factor		30			30		%
e _n	Equivalent input noise voltage $f = 1 \text{ kHz}, R_s = 100 \Omega$		38			38		<u>nV</u> √Hz
V _{o1} /V _{o2}	Channel separation		120			120		dB

^{1.} Maximum values including unavoidable inaccuracies of industrial tests.

3 Typical characteristics

Figure 2. Supply current (each amplifier) versus supply voltage

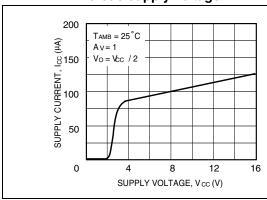


Figure 3. Input bias current versus free air temperature

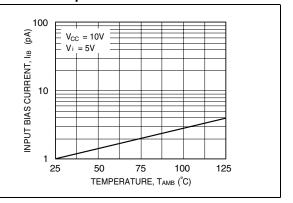


Figure 4. High level output voltage versus high level output current

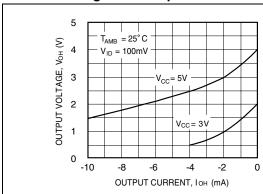


Figure 5. High level output voltage versus high level output current

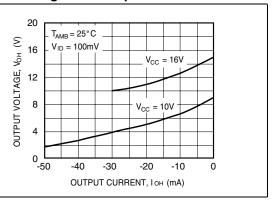
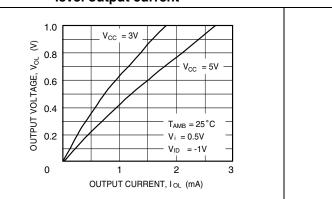


Figure 6. Low level output voltage versus low Figure 7. level output current



Low level output voltage versus low level output current

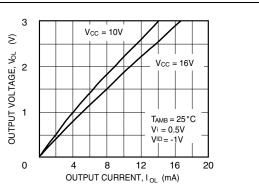
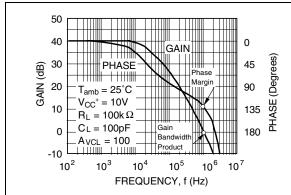


Figure 8. Open-loop frequency response and Figure 9. Gain bandwidth product versus phase shift supply voltage



T_{amb} = 25°C R_L = 100kΩ C_L = 100pF A_V = 1 SUPPLY VOLTAGE, V_{CC} (V)

Figure 10. Phase margin versus supply voltage

Figure 11. Phase margin versus capacitive load

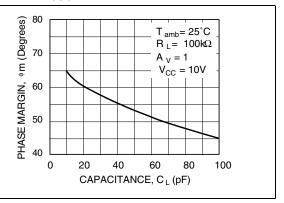


Figure 12. Slew rate versus supply voltage

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SUPPLY VOLTAGE, V_{CC} (V)

12

16

4

0

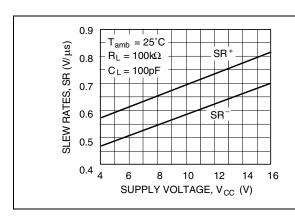
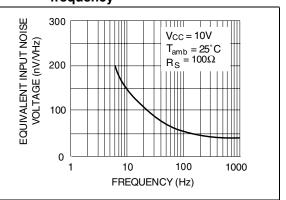


Figure 13. Input voltage noise versus frequency



4 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

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4.1 DIP8 package information

Figure 14. DIP8 package mechanical drawing

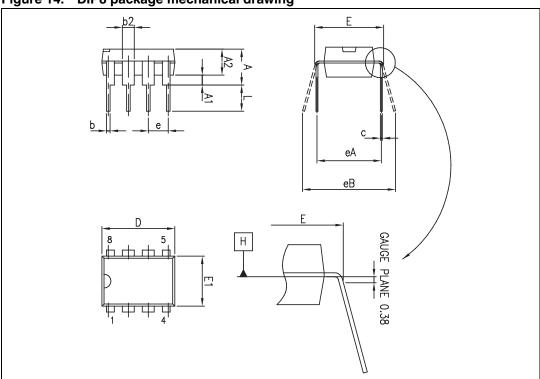


Table 4. DIP8 package mechanical data

			Dimer	nsions		
Ref.		Millimeters			Inches	
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α			5.33			0.210
A1	0.38			0.015		
A2	2.92	3.30	4.95	0.115	0.130	0.195
b	0.36	0.46	0.56	0.014	0.018	0.022
b2	1.14	1.52	1.78	0.045	0.060	0.070
С	0.20	0.25	0.36	0.008	0.010	0.014
D	9.02	9.27	10.16	0.355	0.365	0.400
Е	7.62	7.87	8.26	0.300	0.310	0.325
E1	6.10	6.35	7.11	0.240	0.250	0.280
е		2.54			0.100	
eA		7.62			0.300	
eB			10.92			0.430
L	2.92	3.30	3.81	0.115	0.130	0.150

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4.2 SO-8 package information

Figure 15. SO-8 package mechanical drawing

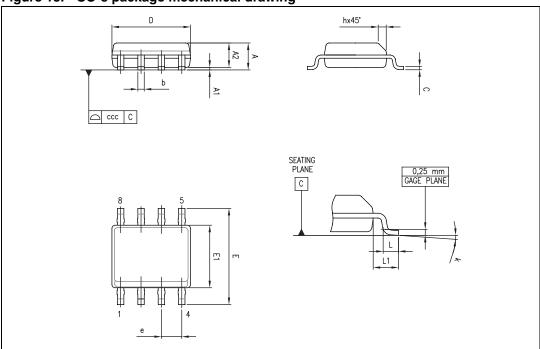


Table 5. SO-8 package mechanical data

			Dime	nsions		
Ref.		Millimeters			Inches	
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α			1.75			0.069
A1	0.10		0.25	0.004		0.010
A2	1.25			0.049		
b	0.28		0.48	0.011		0.019
С	0.17		0.23	0.007		0.010
D	4.80	4.90	5.00	0.189	0.193	0.197
E	5.80	6.00	6.20	0.228	0.236	0.244
E1	3.80	3.90	4.00	0.150	0.154	0.157
е		1.27			0.050	
h	0.25		0.50	0.010		0.020
L	0.40		1.27	0.016		0.050
L1		1.04			0.040	
k	1°		8°	1°		8°
ccc			0.10			0.004

4.3 TSSOP8 package information

Figure 16. TSSOP8 package mechanical drawing

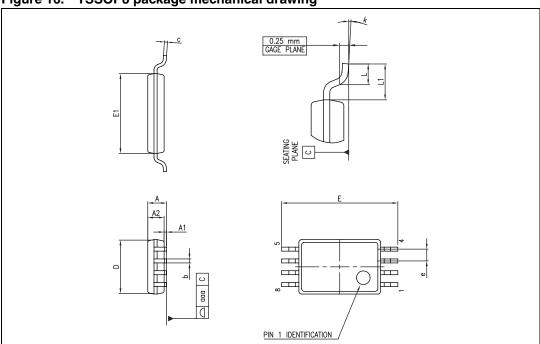


Table 6. TSSOP8 package mechanical data

			Dimer	nsions		
Ref.		Millimeters			Inches	
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α			1.20			0.047
A1	0.05		0.15	0.002		0.006
A2	0.80	1.00	1.05	0.031	0.039	0.041
b	0.19		0.30	0.007		0.012
С	0.09		0.20	0.004		0.008
D	2.90	3.00	3.10	0.114	0.118	0.122
Е	6.20	6.40	6.60	0.244	0.252	0.260
E1	4.30	4.40	4.50	0.169	0.173	0.177
е		0.65			0.0256	
k	0°		8°	0°		8°
L	0.45	0.60	0.75	0.018	0.024	0.030
L1		1			0.039	
aaa			0.10			0.004

5 Ordering information

Table 7. Order codes

Part number	Temperature range	Package	Packing	Marking
TS27M2CD TS27M2CDT		SO-8	Tube Tape & reel	27M2C
TS27M2CN		DIP8	Tube	TS27M2CN
TS27M2CPT		TSSOP8	Tube Tape & reel	27M2C
TS27M2ACD TS27M2ACDT	0° C to +70° C	SO-8	Tube Tape & reel	27M2AC
TS27M2ACN		DIP8	Tube	S27M2ACN
TS27M2ACPT		TSSOP8	Tape & reel	2M2AC
TS27M2BCD TS27M2BCDT		SO-8	Tube Tape & reel	27M2BC
TS27M2BCN		DIP8	Tube	S27M2BCN
TS27M2BCPT		TSSOP8	Tape & reel	2M2BC
TS27M2ID TS27M2IDT		SO-8	Tube Tape & reel	27M2I
TS27M2IN		DIP8	Tube	TS27M2IN
TS27M2IPT		TSSOP8	Tape & reel	27M2I
TS27M2AID TS27M2AIDT	100 0	SO-8	Tube Tape & reel	27M2AI
TS27M2AIN	-40° C to +125° C	DIP8	Tube	S27M2AIN
TS27M2AIPT		TSSOP8	Tape & reel	2M2AI
TS27M2BID TS27M2BIDT		SO-8	Tube Tape & reel	27M2BI
TS27M2BIN		DIP8	Tube	S27M2BIN
TS27M2BIPT		TSSOP8	Tape & reel	2M2BI

6 Revision history

Table 8. Document revision history

Date	Revision	Changes
01-Nov-2001	1	Initial release.
18-Aug-2009	2	Updated document format. Added ESD and Rthja information in <i>Table 1: Absolute maximum ratings</i> . Removed block diagram. Added minimum values for Io, GBP and SR parameters in <i>Table 3</i> . Added order codes in <i>Table 7</i> .

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